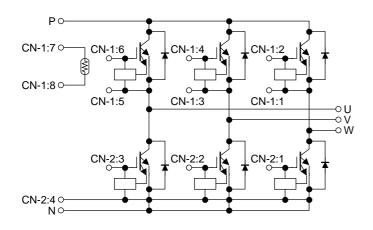
TOSHIBA GTR Module Silicon N Channel IGBT

# MG200J6ES60(600V/200A 6in1)

High Power Switching Applications Motor Control Applications

- Integrates inverter power circuit in to a single package.
- The electrodes are isolated from case.
- Low thermal resistance
- VCE (sat) = 1.6 V (typ.)

# **Equivalent Circuit**



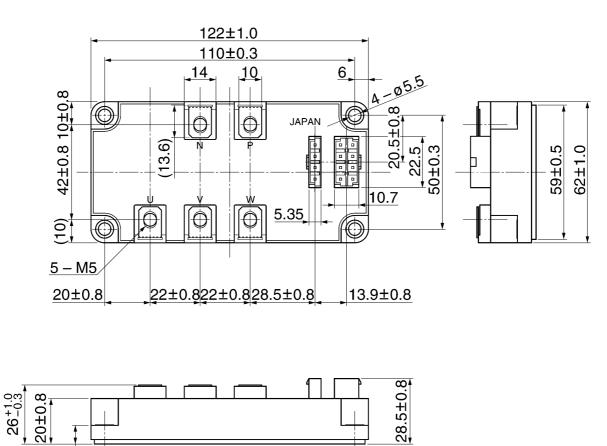
## **Signal Terminal**

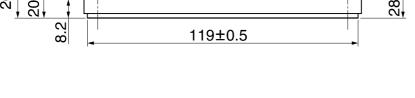
CN-	1						
1.	E (W)	2.	G (W)	3.	E (V)	4.	G (V)
5.	E (U)	6.	G (U)	7.	TH1	8.	TH2
CN-	2						
1.	G (Z)	2.	G (Y)	3.	G (X)	4.	E (L)

**TOSHIBA** 

## Package Dimensions: 2-123B1A

Unit: mm





1 3 5 7	CN-1			
0000	1. E(W)	2. G (W)	3. E (V)	4. G (V)
0000	5. E (U)	6. G (U)	7. TH1	8. TH2
2 4 6 8				
4 3 2 1	CN-2			
0000	1. G (Z)	2. G (Y)	3. G (X)	4. E (L)

# Maximum Ratings (Ta = 25°C)

Stage	Characteristics	Symbol	Rating	Unit		
	Collector-emitter voltage	V <sub>CES</sub>	600	V		
	Gate-emitter voltage	V <sub>GES</sub>	±20	V		
	Collector current	DC	Ι <sub>C</sub>	200	A	
Inverter		1 ms	I <sub>CP</sub>	400		
	Forward current DC 1 ms		١ <sub>F</sub>	200	A	
			I <sub>FM</sub>	400		
	Collector power dissipation (Tc =	PC	1000	W		
	Junction temperature	Тј	150	°C		
Module	Storage temperature range	T <sub>stg</sub>	-40~125	°C		
wodule	Isolation voltage	V <sub>isol</sub>	2500 (AC 1 min)	V		
	Screw torque	—	3 (M5)	N∙m		

# Electrical Characteristics (T<sub>j</sub> = 25°C)

## 1. Inverter stage

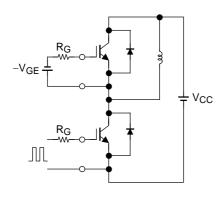
Characteristics		Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	$V_{GE}=\pm 20~V,~V_{CE}=0$		_	—	±500	nA
Collector cut-off current		ICES	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$		_	_	1.0	mA
Gate-emitter cut-off voltage		V <sub>GE</sub> (off)	$V_{CE} = 5 \text{ V}, I_{C} = 200 \text{ mA}$		5.0	6.5	8.0	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	V <sub>GE</sub> = 15 V, I <sub>C</sub> = 200 A	$T_j = 25^{\circ}C$	_	1.6	2.2	V
				T <sub>j</sub> = 125°C	_	_	2.2	v
Input capacitance		C <sub>ies</sub>	$V_{CE} = 10 \text{ V}, \text{ V}_{GE} = 0, \text{ f} = 1 \text{ MHz}$		_	33000	_	pF
Switching time	Turn-on delay time	t <sub>d (on)</sub>			_	_	1.00	
	Turn-off time	t <sub>off</sub>	$V_{CC} = 300 \text{ V}, I_{C} = 100 \text{ V}$		_	_	1.20	
	Fall time	t <sub>f</sub>	$V_{GE} = \pm 15 \text{ V}, \text{ R}_{G} = 10$		(Note 1)	_	_	0.50
Reverse recovery time		t <sub>rr</sub>	]			_	0.30	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 200 A			1.7	2.3	V

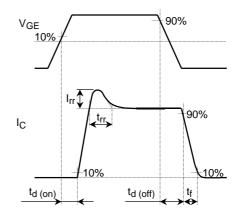
Note 1: Switching time test circuit & timing chart

#### 2. Module (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Zero-power resistance	R25	ITM = 0.2 mA	_	100	_	kΩ	
B value	B25/85	Tc = 25°C/Tc = 85°C	_	4390	_	К	
Junction to case thermal resistance	R <sub>th (j-c)</sub>	Inverter IGBT stage	_	_	0.125	°C/W	
Sunction to case thermal resistance		Inverter FRD stage	_	_	0.195	C/VV	
Case to fin thermal resistance	R <sub>th (c-f)</sub>	—		0.05		°C/W	

# Switching Time Test Circuit & Timing Chart





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Handbook" etc.,

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